2SC1907

Silicon NPN Epitaxial Planar

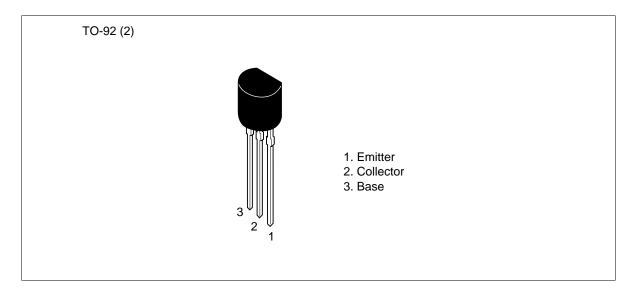
HITACHI

ADE-208-1059 (Z) 1st. Edition Mar. 2001

Application

UHF TV Tuner, Local oscillator

Outline





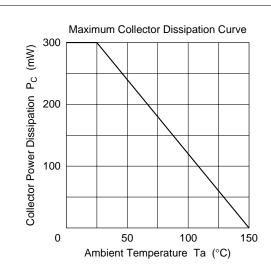
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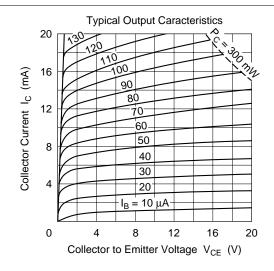
Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

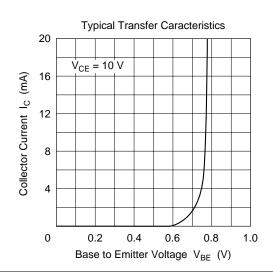
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	30	V
Collector to emitter voltage	V _{CEO}	19	V
Emitter to base voltage	V_{EBO}	2	V
Collector current	I _c	50	mA
Emitter current	I _E	– 50	mA
Collector power dissipation	P _c	300	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

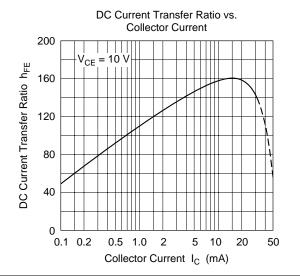
Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	30	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	19	_	_	V	$I_{C} = 3 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	2	_	_	V	$I_{E} = 10 \ \mu A, \ I_{C} = 0$
Collector cutoff current	I _{CBO}	_	_	0.5	μΑ	$V_{CB} = 10 \text{ V}, I_{E} = 0$
DC current transfer ratio	h_{FE}	40	_	_		$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	0.2	1.0	V	$I_C = 20 \text{ mA}, I_B = 4 \text{ mA}$
Collector output capacitance	Cob	_	1.0	2.0	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Gain bandwidth product	f _T	900	1100	_	MHz	$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$
Base time constant	r _{bb′} ⋅C _C	_	10	25	ps	$V_{CB} = 10 \text{ V}, I_{C} = 10 \text{ mA},$ f = 31.8 MHz
Oscillation output power	P _{out}	_	8	_	mW	$V_{CB} = 10 \text{ V}, I_{C} = 10 \text{ mA},$ f = 930 MHz

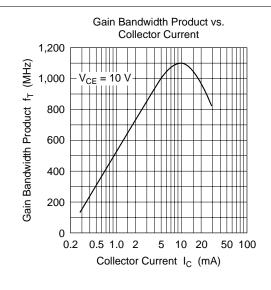


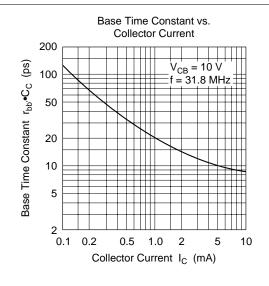


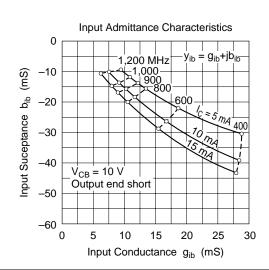


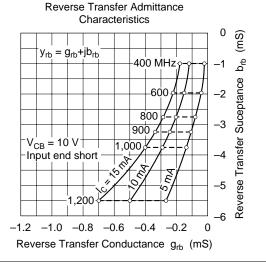


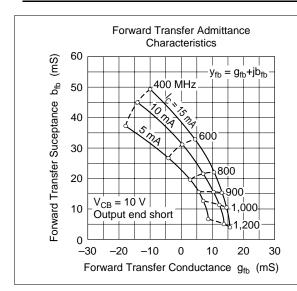
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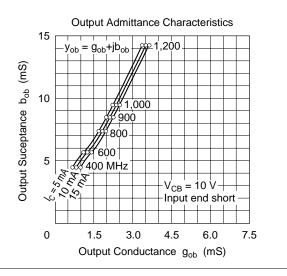




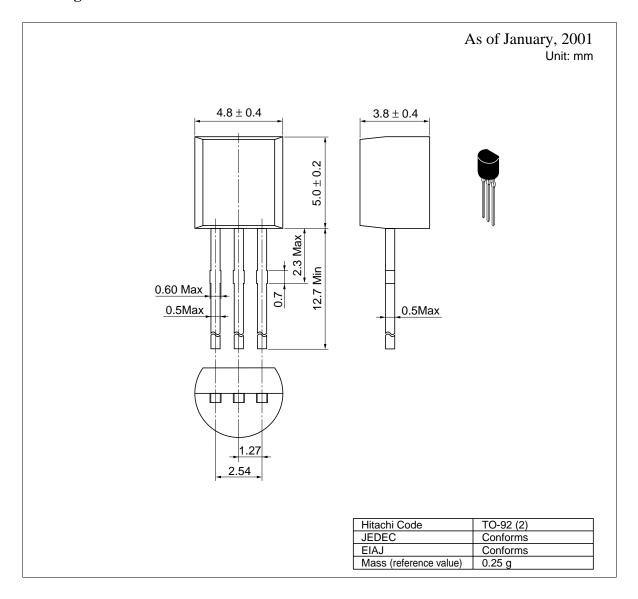








Package Dimensions



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